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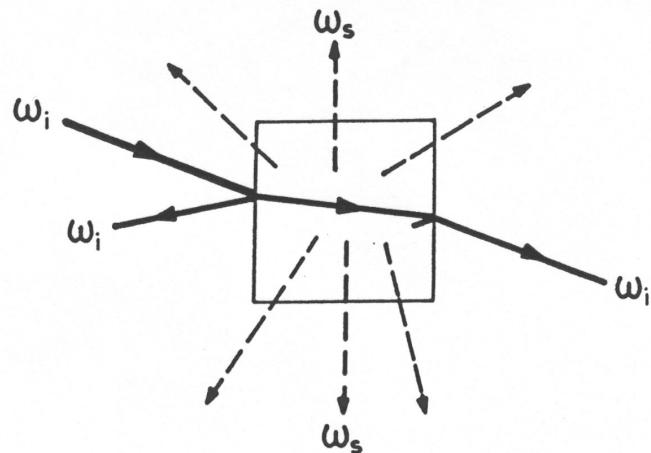
***Linear optical techniques at NAST:  
High Spatial Resolution Raman Scattering (HSRRS)  
and Reflectance Anisotropy Spectroscopy (RAS)***

Wolfgang Richter

Eugen Speiser, Benjamin Buick, Silvano DelGobbo, Regula Lichtenegger,  
Markus Breusing, Linda Riele, Vasiliki Stamelou,  
Claudio Goletti, Beatrice Bonanni, Gianlorenzo Bussetti, Piero Chiaradia,  
Sarah Cirilli, Adriano Violante

***NAST and U Roma „Tor Vergata“***

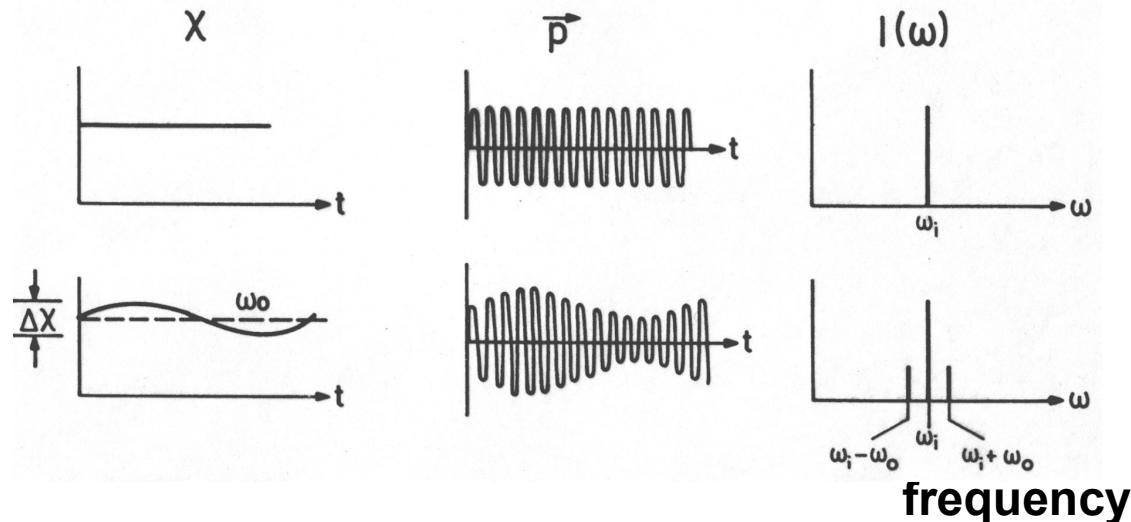
## Raman Scattering: inelastic light scattering



inelastic scattering

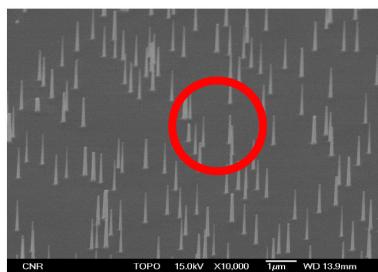
$$\vec{p} = V \cdot \hat{\vec{x}} \cdot \vec{E}_i \exp i\omega_i t$$

— geometrical optics  
(elastic scattering)

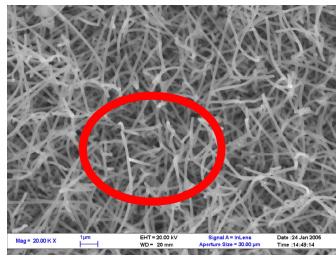


# Why high spatial resolution (nanometer ) Optics?

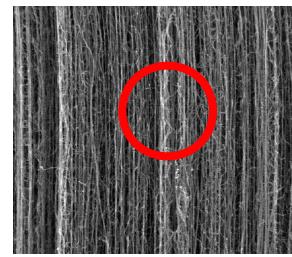
- Epitaxial methods have strongly increased the potential of producing high quality NANO-structures (dots, rods,tubes)



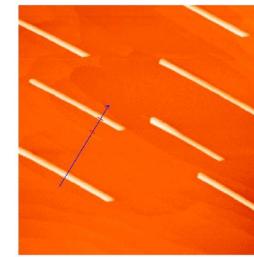
GaAs nanorods



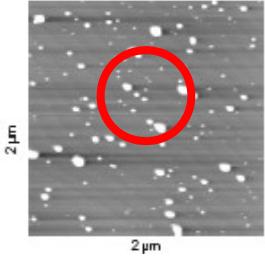
Si –Nano wires



C - nanotubes



Pb - wires



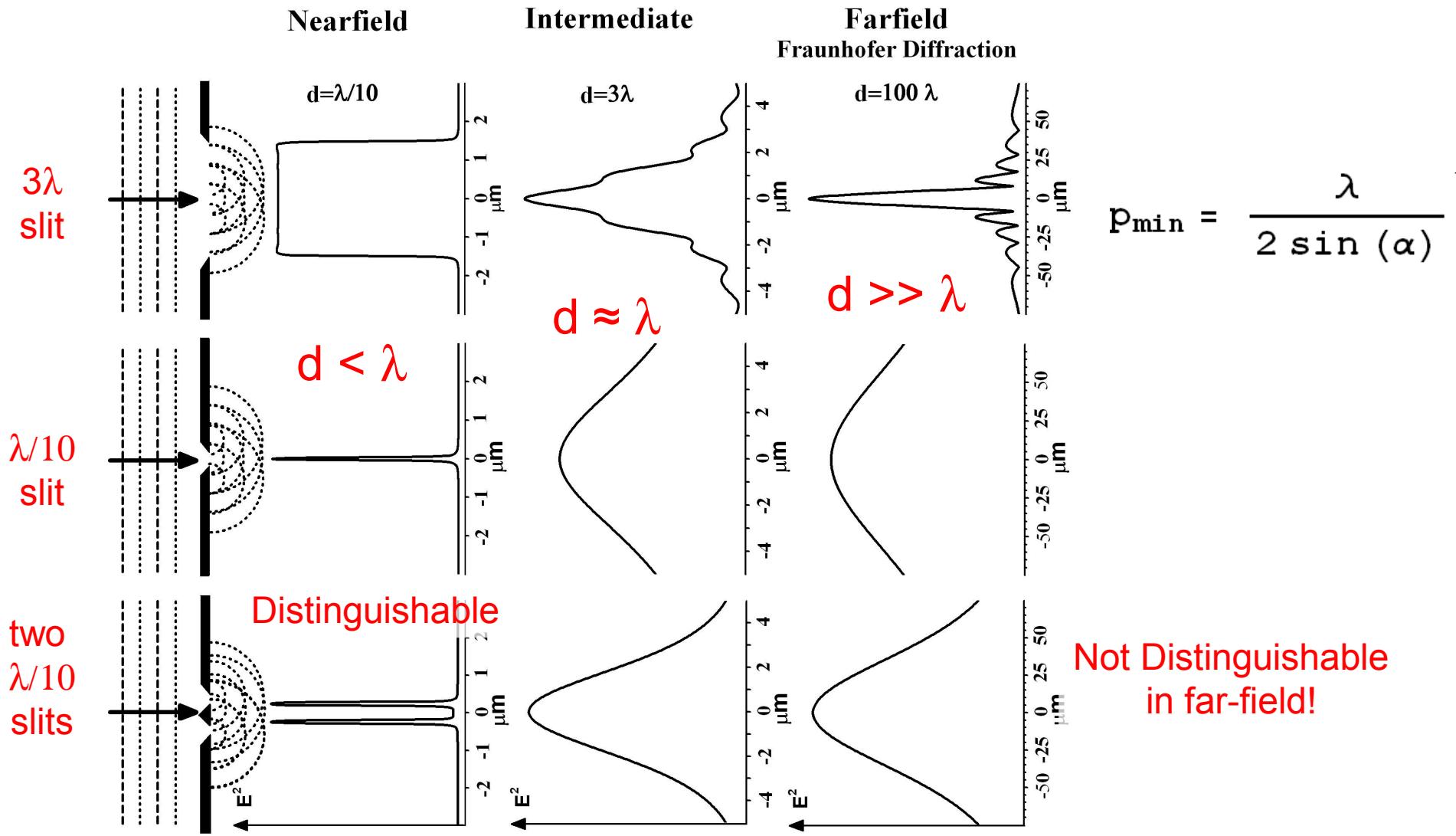
InAs - QDs

- Optical techniques important : optical properties, electronic states, devices
- But: diffraction limit ( $\sim 300$  nm, *Far Field*)  $\gg$  NANO's  $< 30$  nm
- A chance for the optical *NEAR Field* ?

NAST-ISM meeting 22.06.2009

slide -# 3

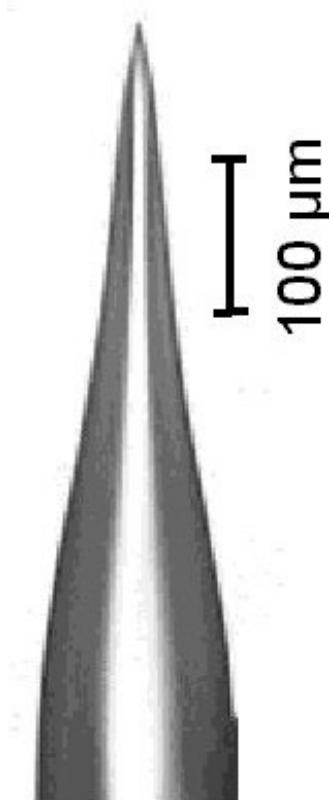
# Resolution Beyond Diffraction Limit: Nearfield



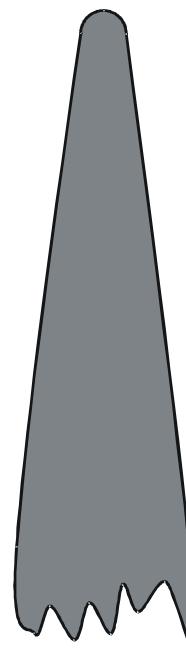
# Optical Nearfield Probes

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Glasfiber

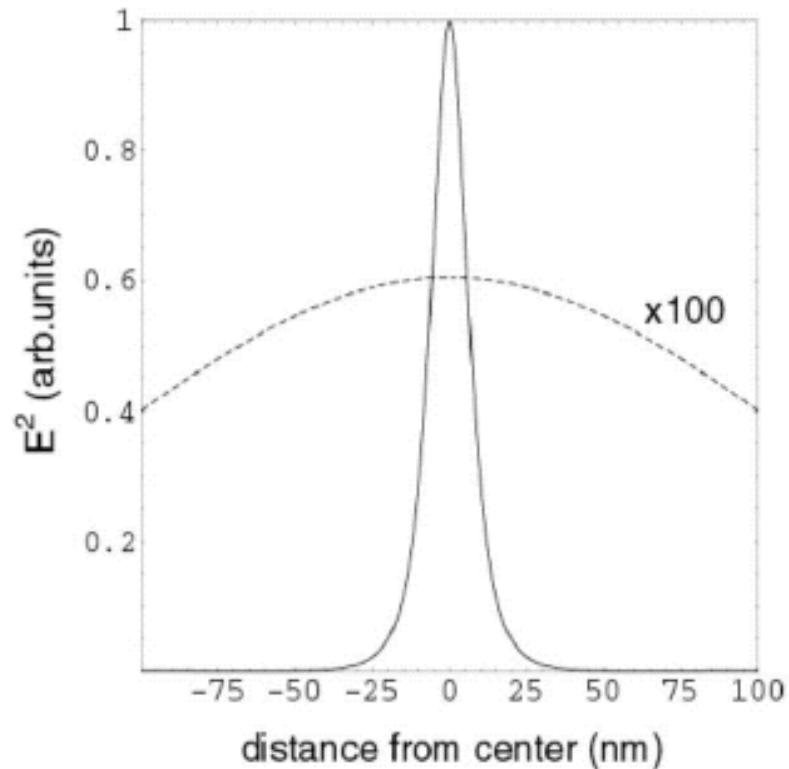
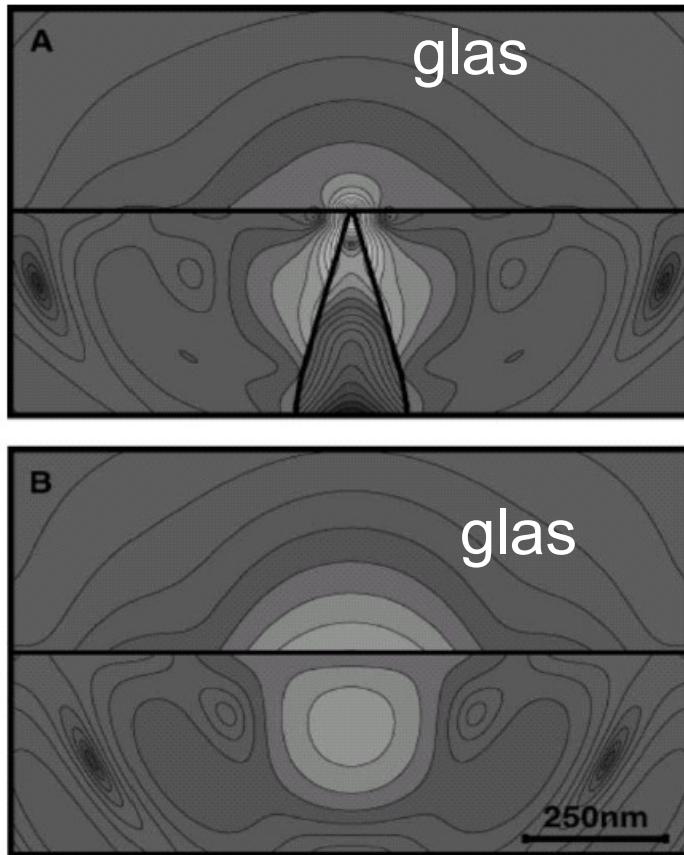


Metallic tip



Tip Diameter ~50 nm

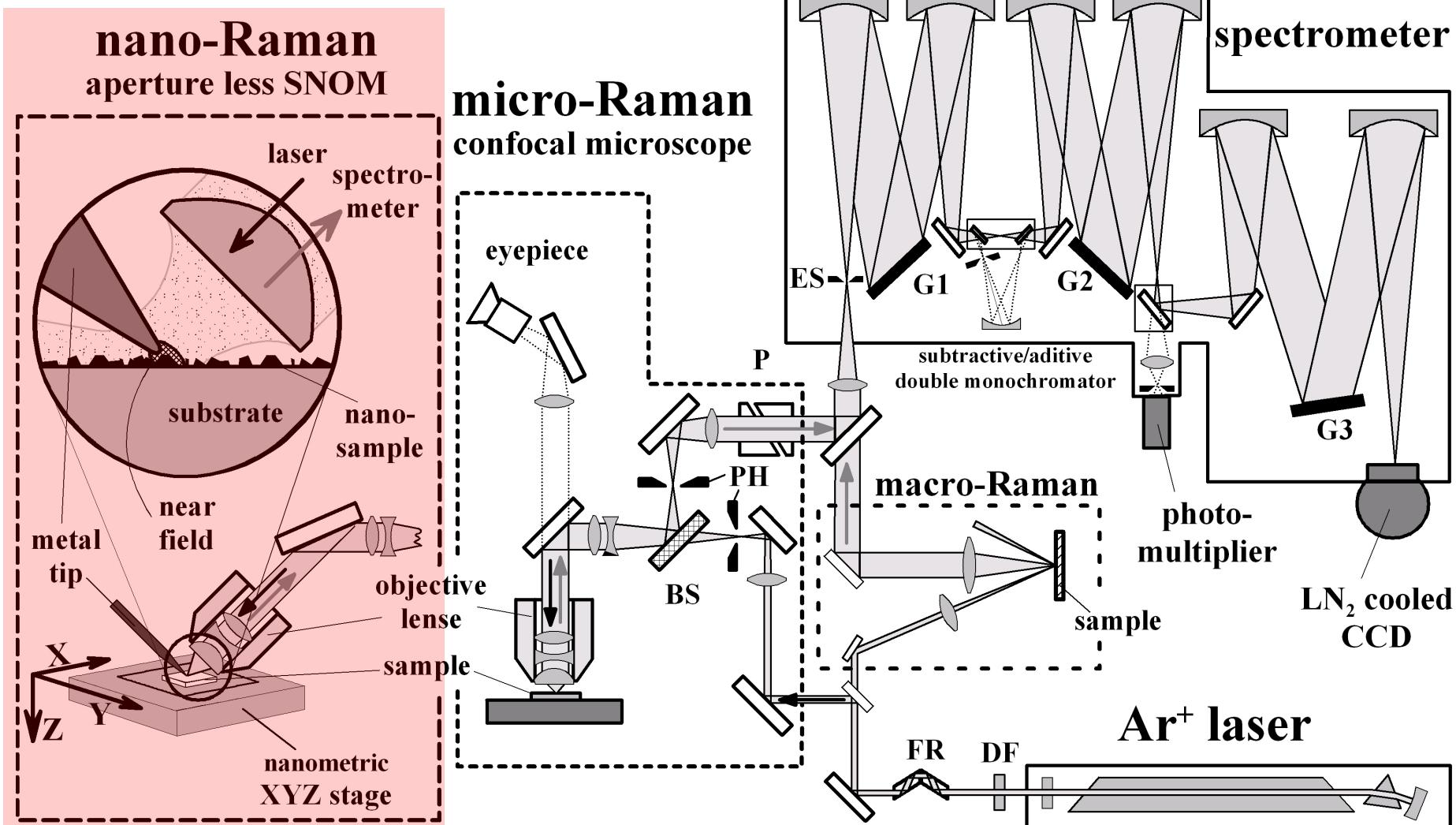
# Plasmonic field enhancement by metal tip



$$\Omega_{\text{Laser}} \sim \Omega_{\text{Plasmon}}$$

Bennett B. et al, IEEE J. SELECTED TOPICS IN QUANTUM ELECTRONICS, VOL. 8, 1051 (2002)

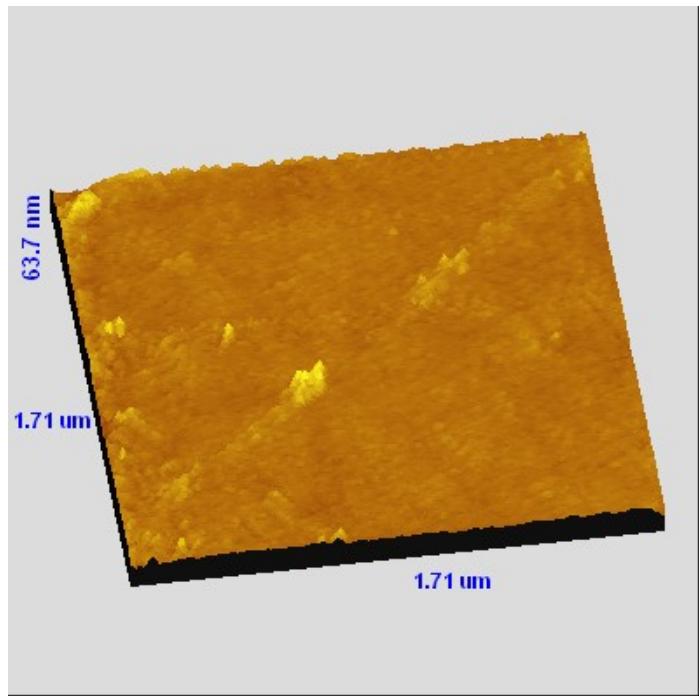
## Raman –optical set-up: Nano, micro, macro



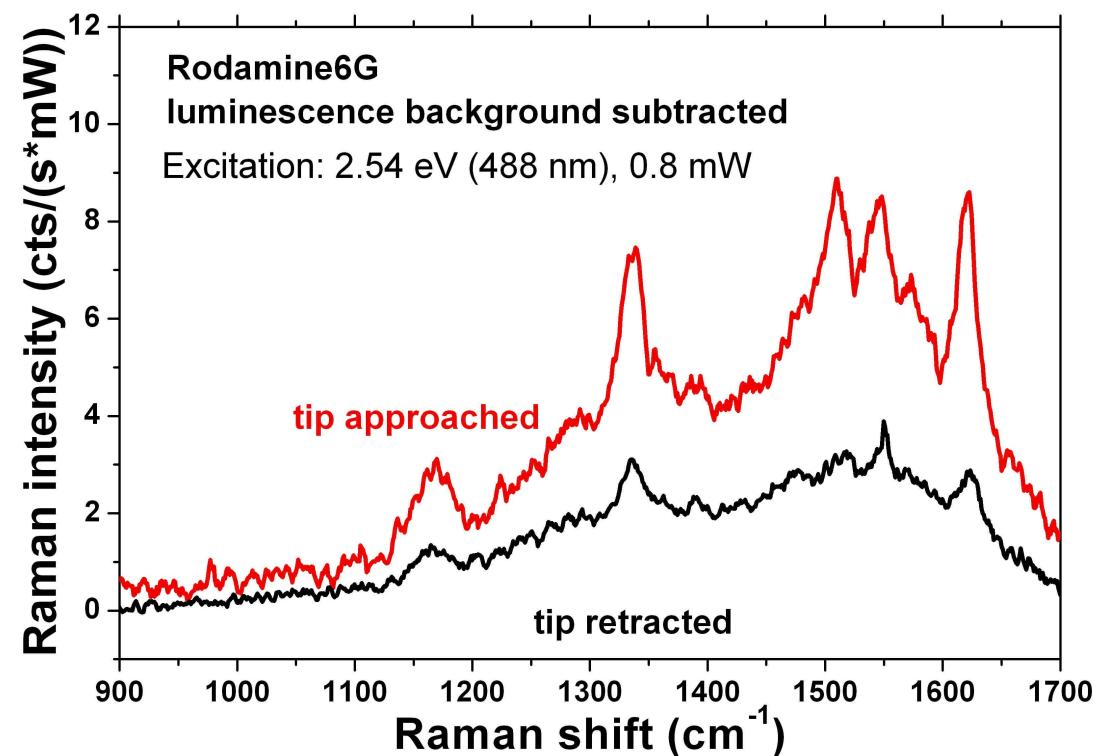


# Rhodamin 6G on Ag(110)

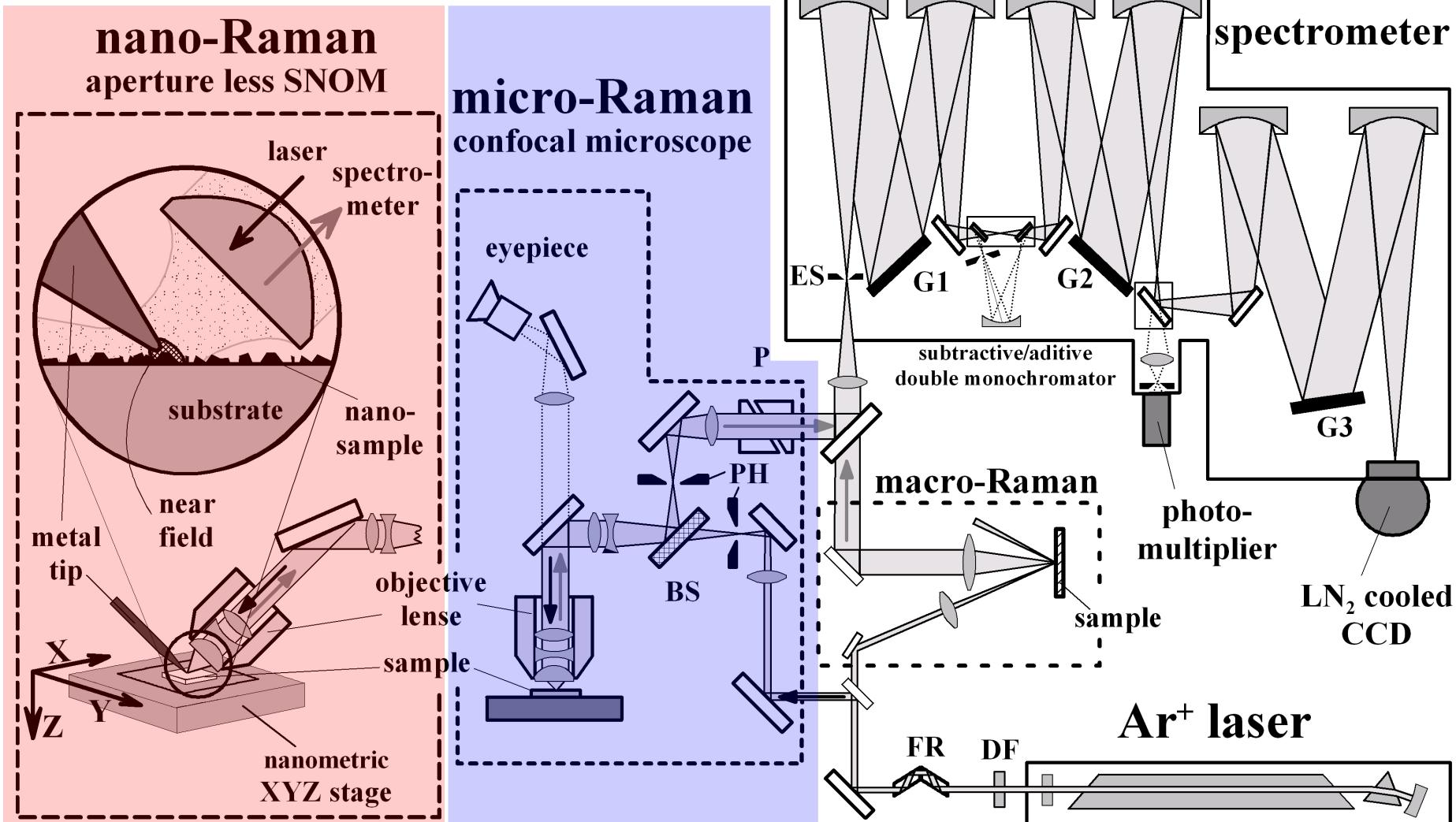
Organic molecules on Ag  
STM image



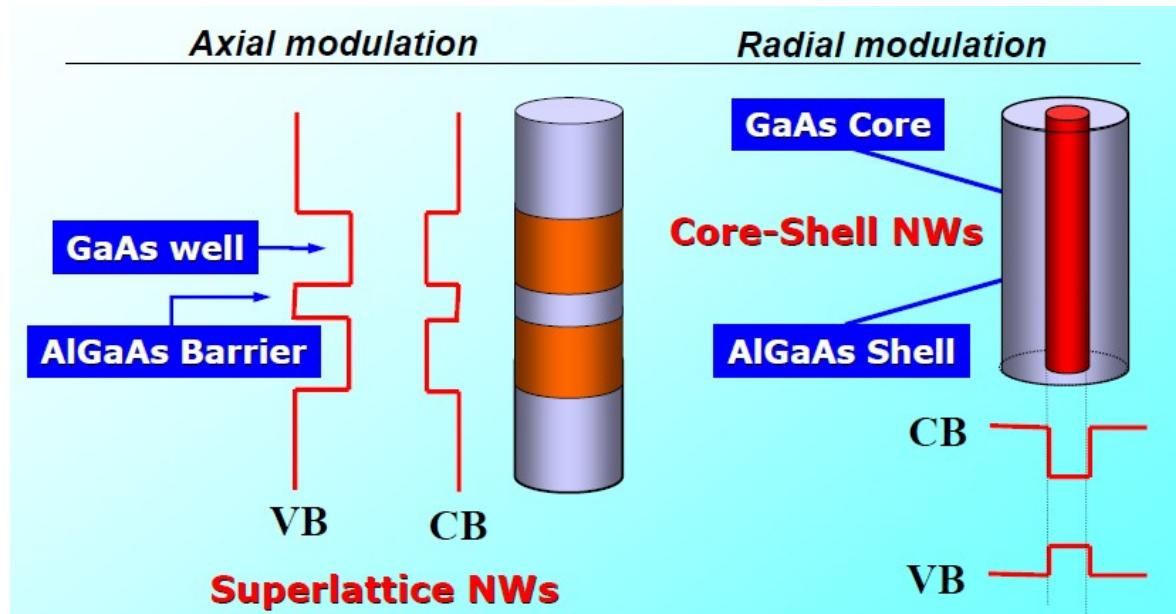
Enhancement of Ramanspectra by metallic Tip



## Raman –optical set-up: Nano, micro, macro



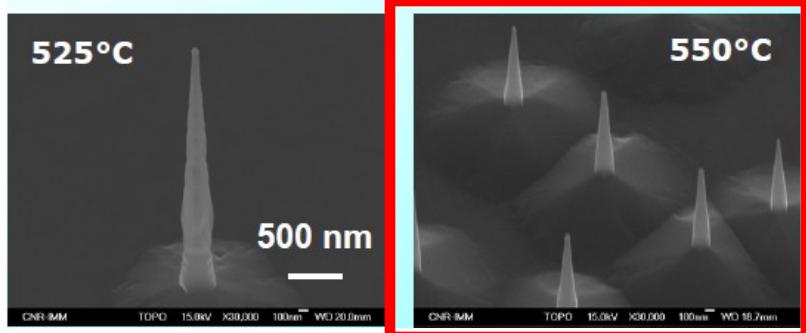
# *AlGaAs nano-structures with heterojunctions*



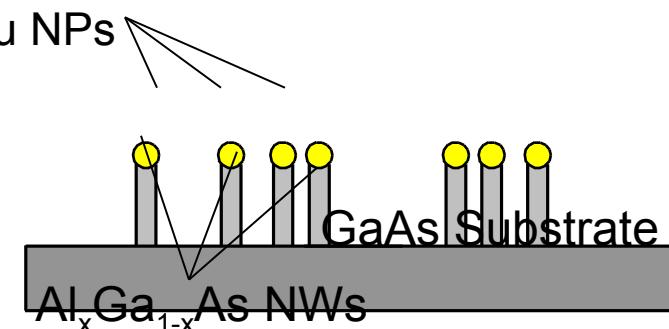
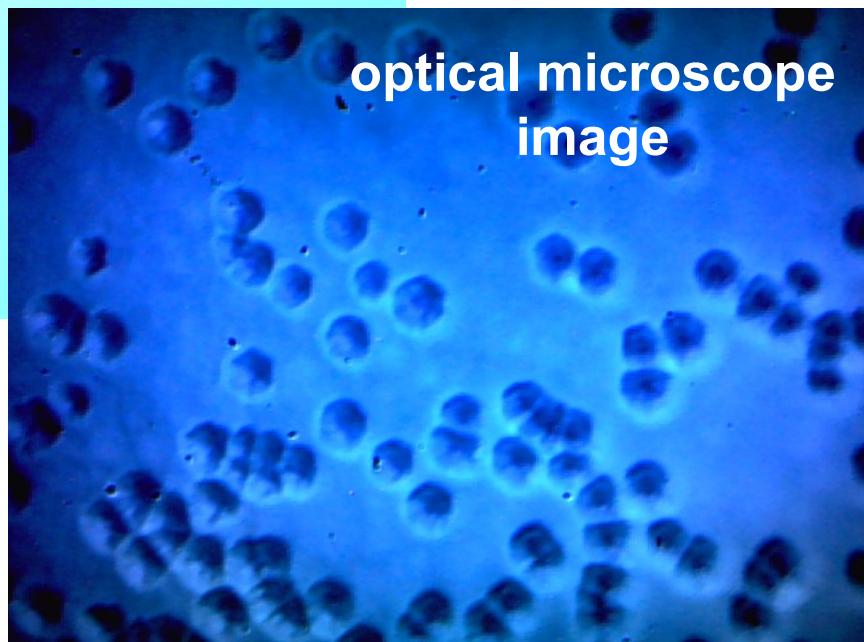
# *“Finding” Single Nanostructures*

free standing  $\text{Al}_x\text{Ga}_{1-x}\text{As}$  NWs

FE-SEM micrographs  
30,000x magnification

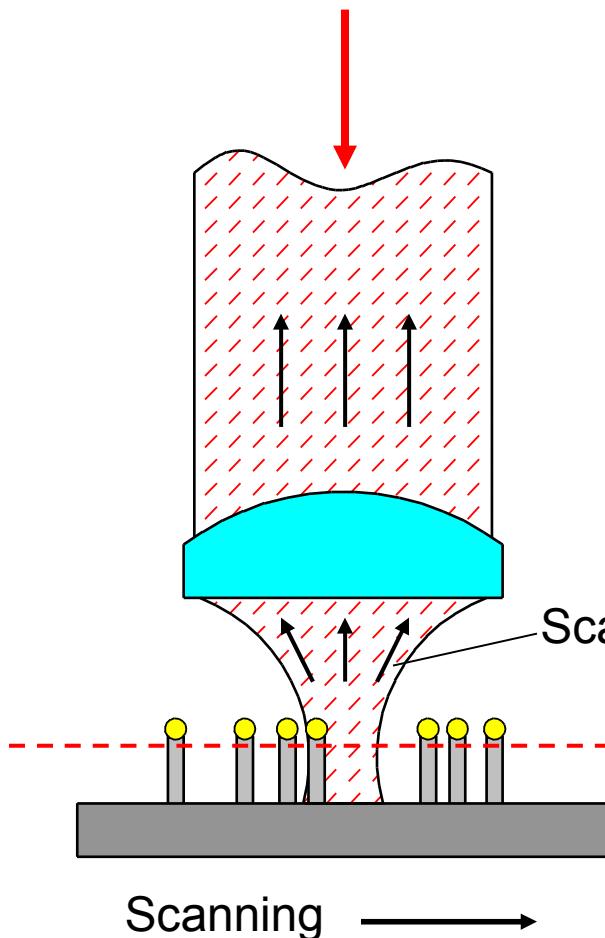


Grown by VLS method at different temperatures with different Al concentration



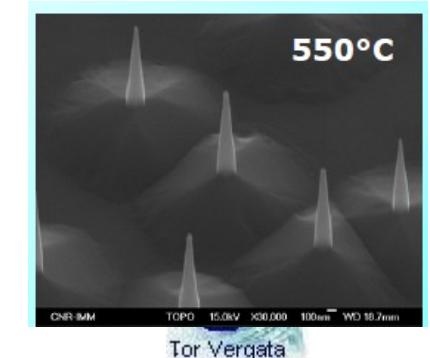
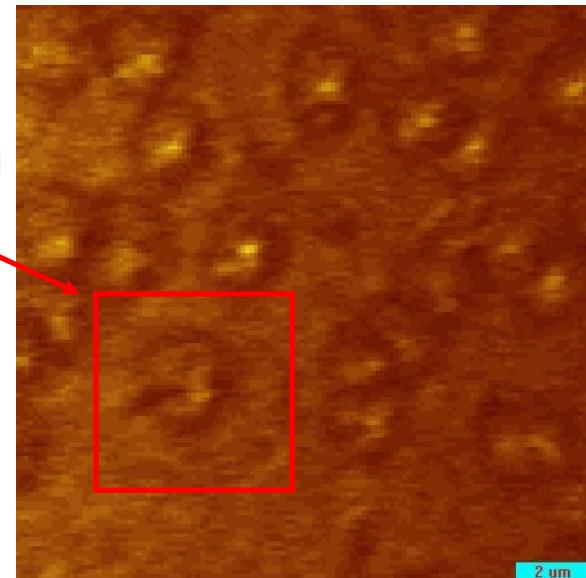
# Rayleigh Imaging of $Al_xGa_{1-x}As$ NWs

Illumination/ Laser



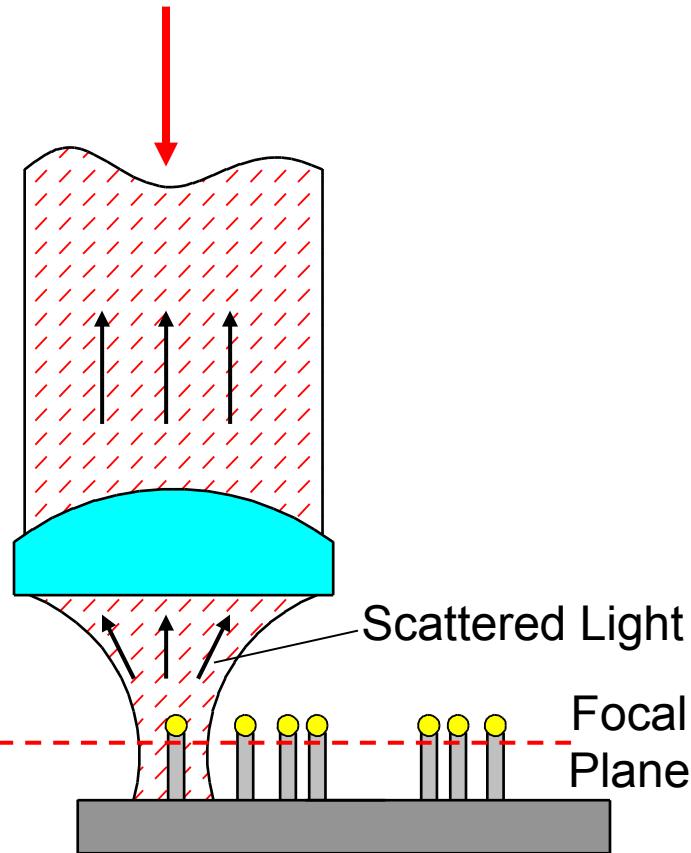
Smaller scanning area

Rayleigh Micrograph

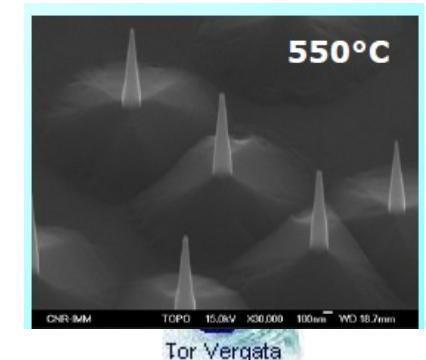
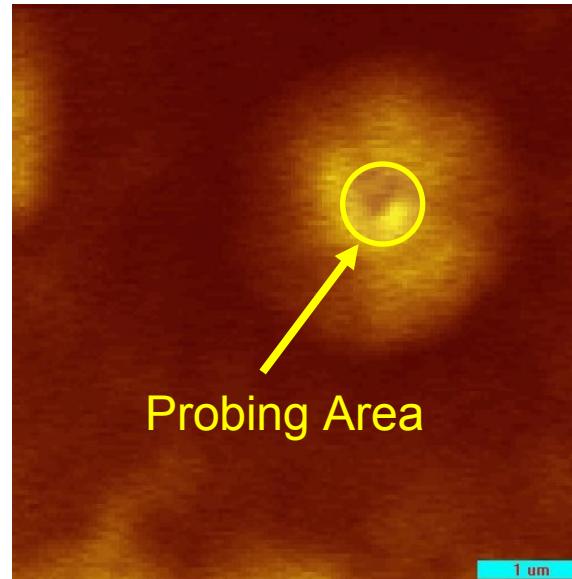


# Raman Spectra of $\text{Al}_x\text{Ga}_{1-x}\text{As}$ NWs

Illumination/ Laser

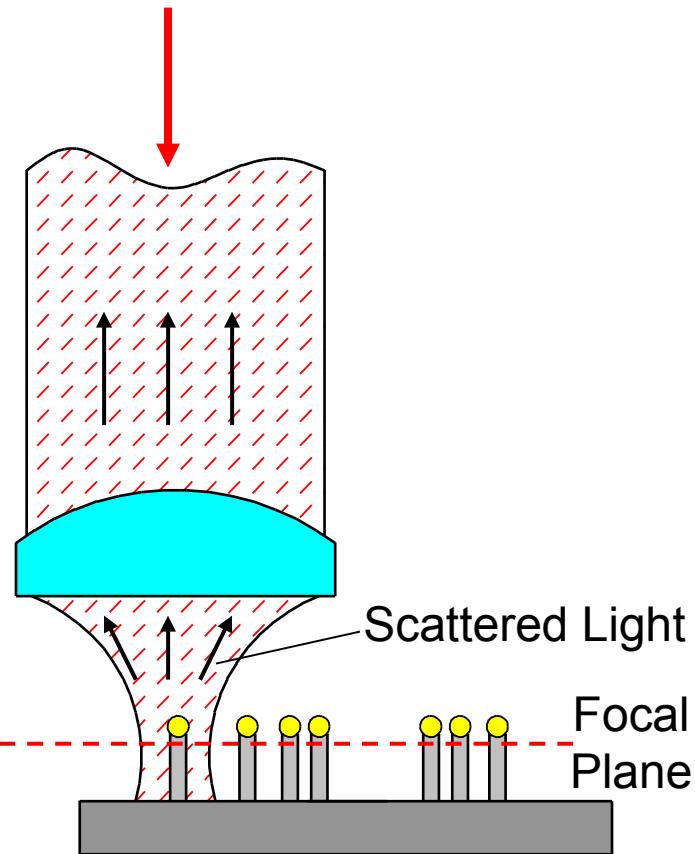


Repositioning

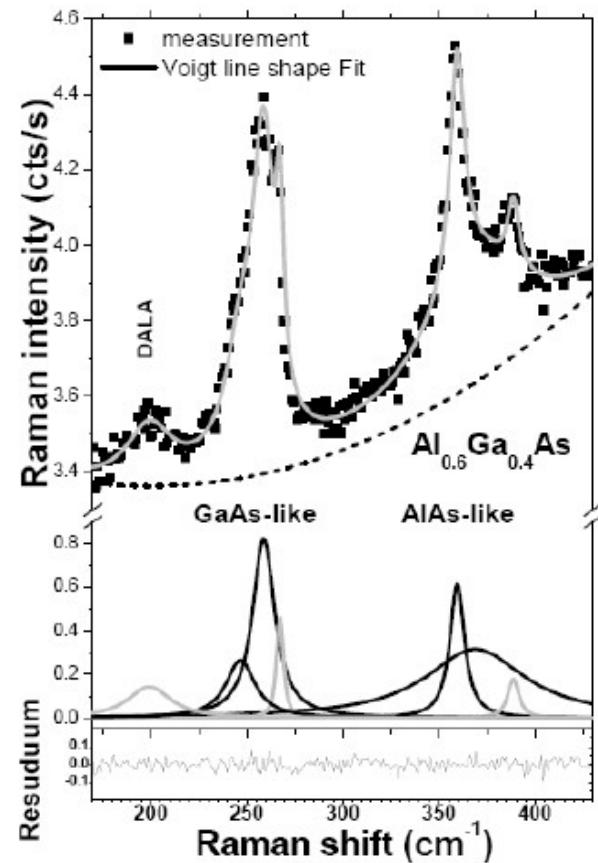


# Raman Spectra of $\text{Al}_x\text{Ga}_{1-x}\text{As}$ NWs

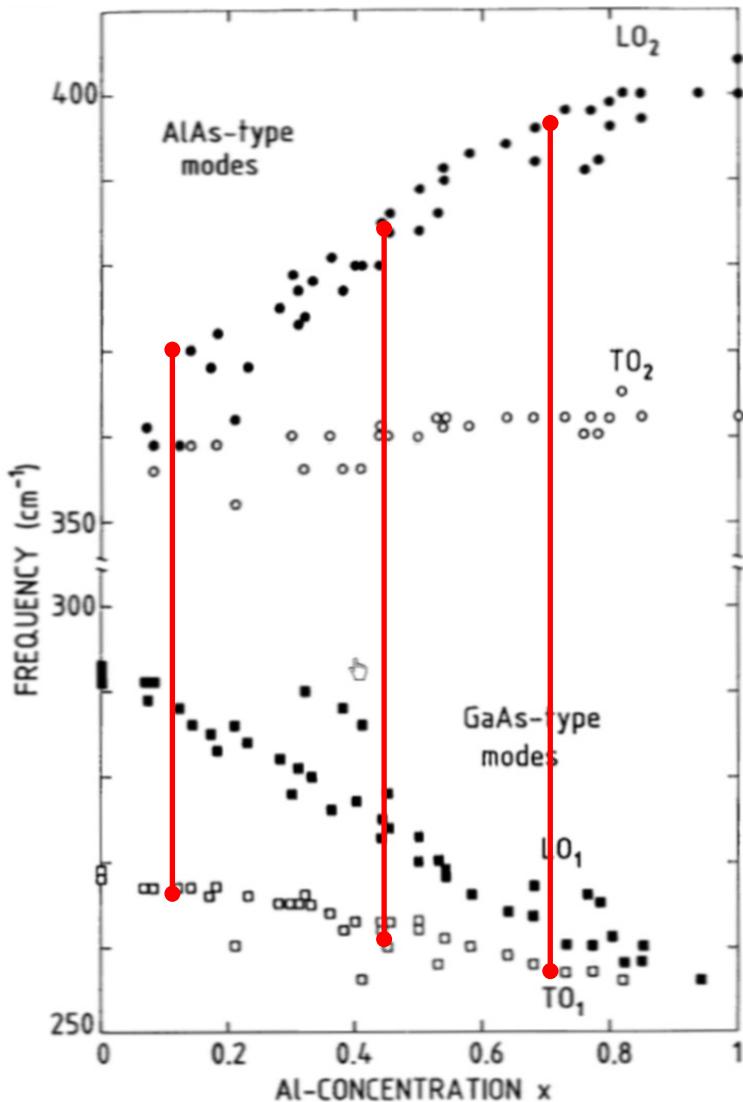
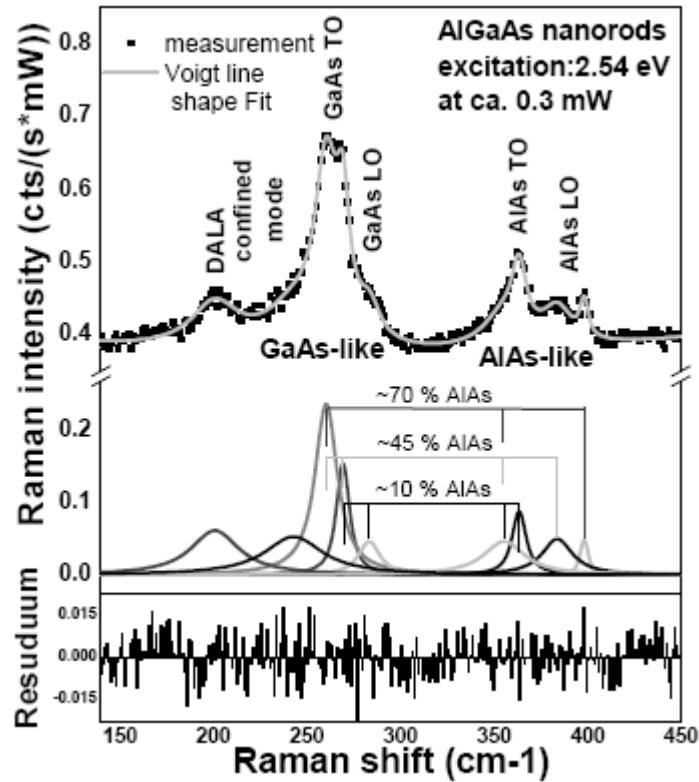
Illumination/ Laser



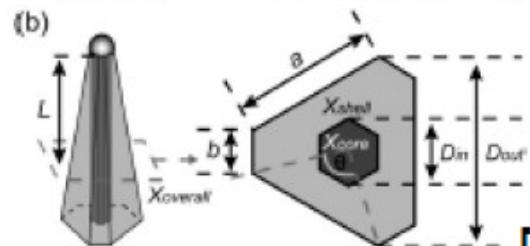
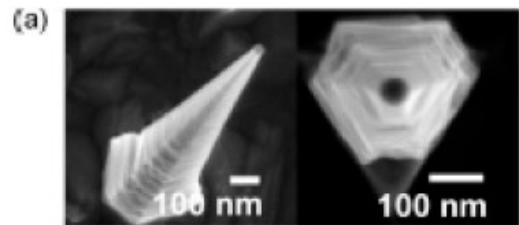
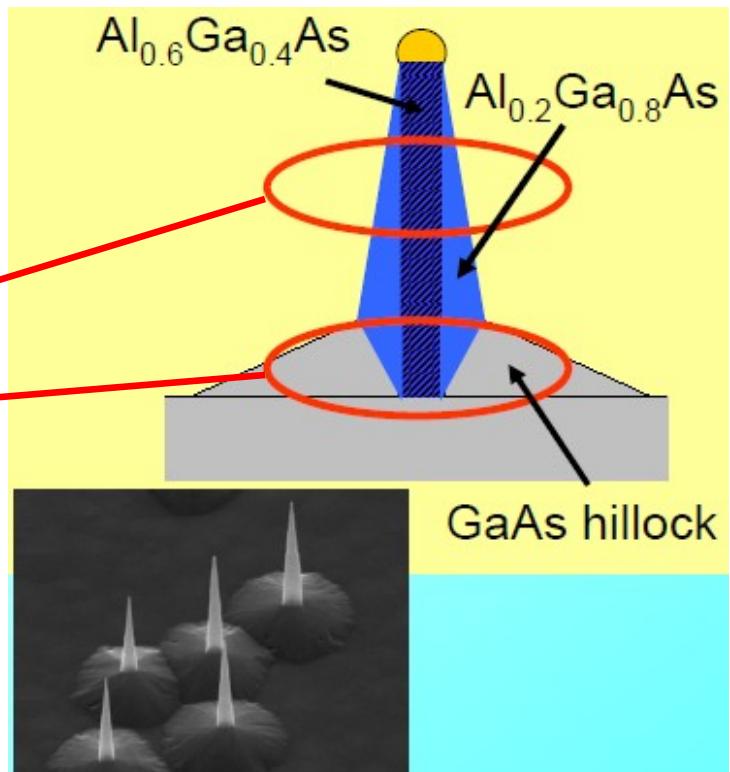
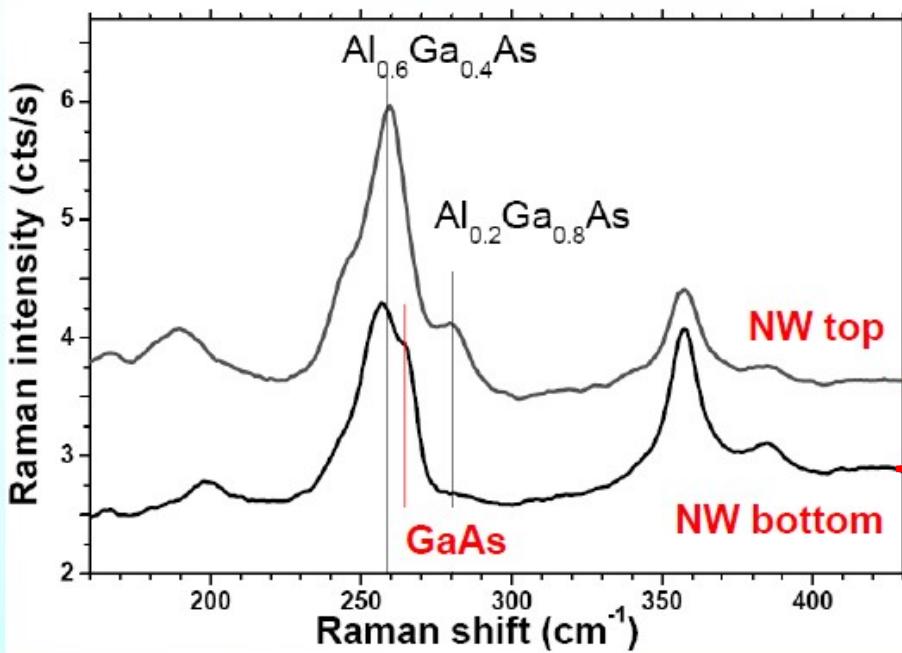
Stable positioning



# Determination of Al Content



## $\mu$ -Raman Spectra at Different Positions Along Wire



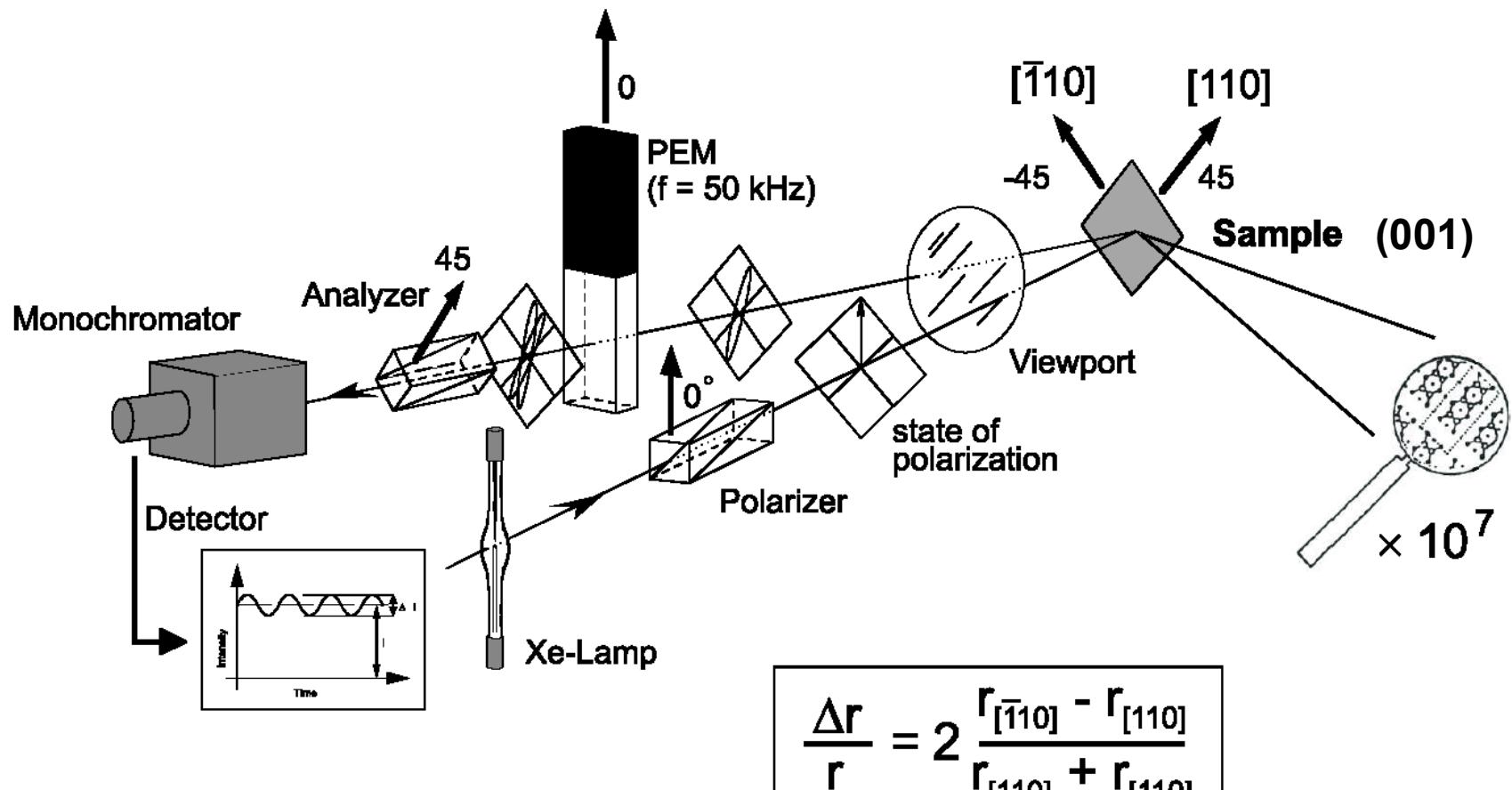
N. Lovergne, NanoSea (2008).

[S.K. Lim et al., Nano Lett. 8 (2008) 1386]

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# Reflectance Anisotropy Spectroscopy on interfaces and thin layers

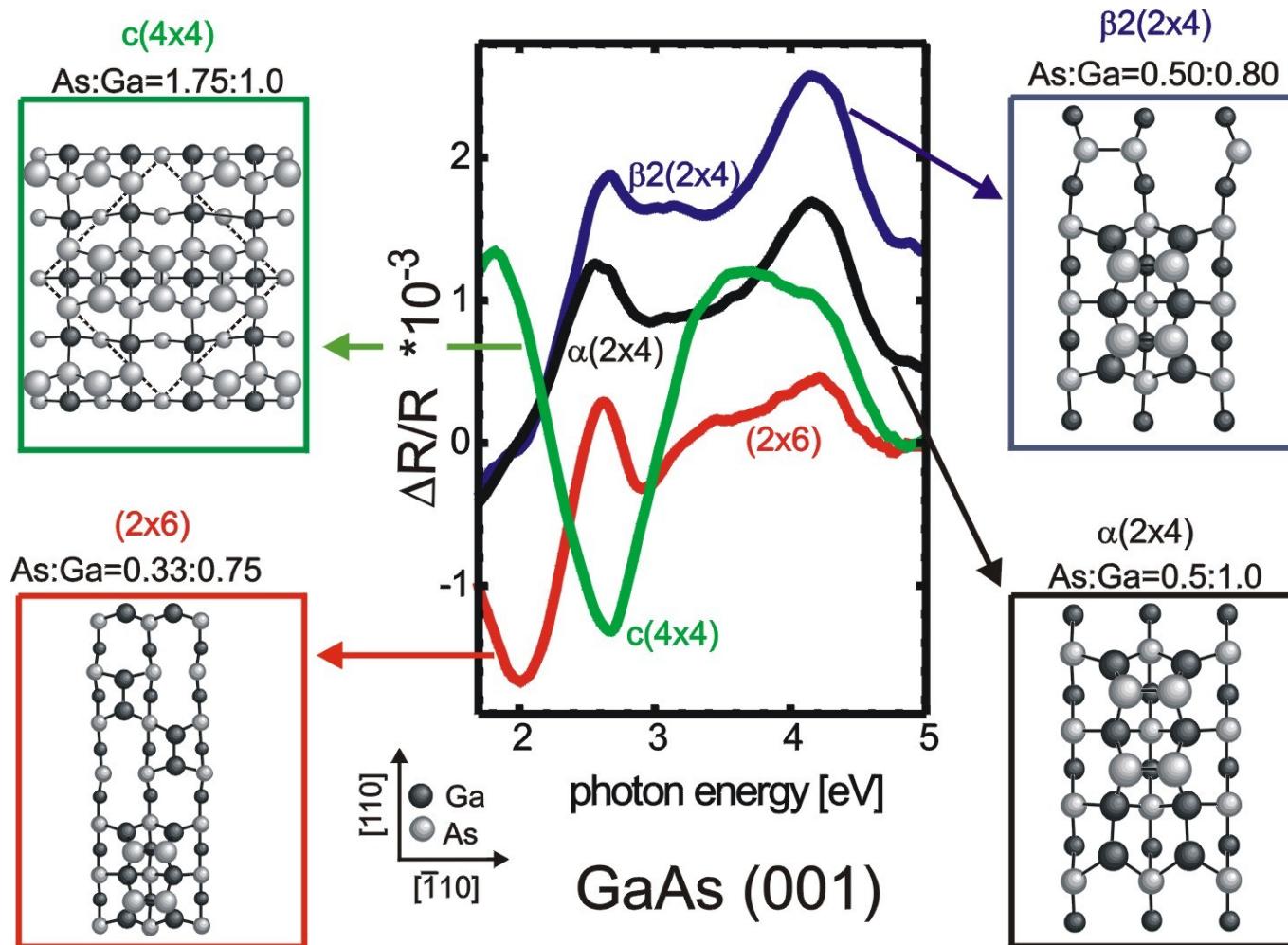
# Reflectance Anisotropy Spectroscopy: setup example



Aspnes 1985

Signal in first order intensity independent !!

# RAS spectra and surface correlation for GaAs(001) surface reconstructions

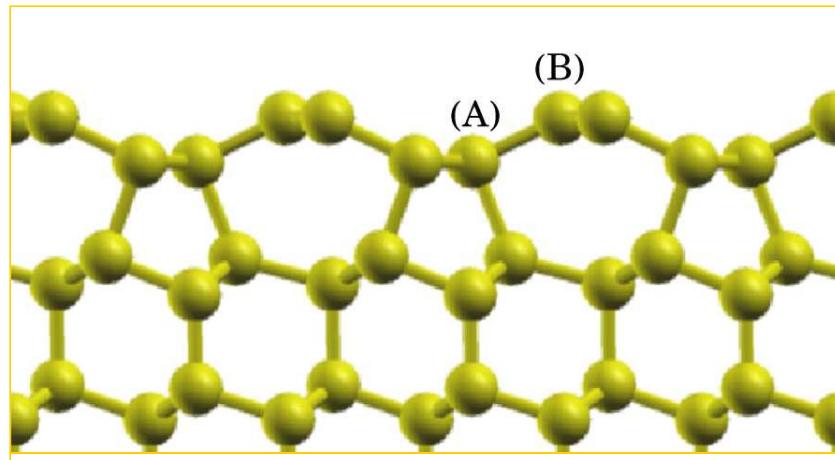


# Geometry of C(111)2x1

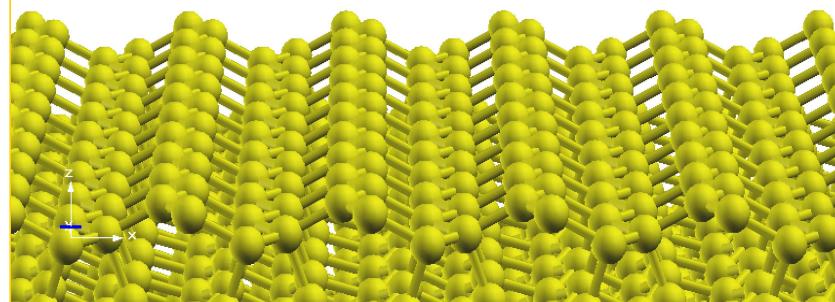
$T_{\text{annealing}} > 1173K$



Pandey Chain Reconstruction

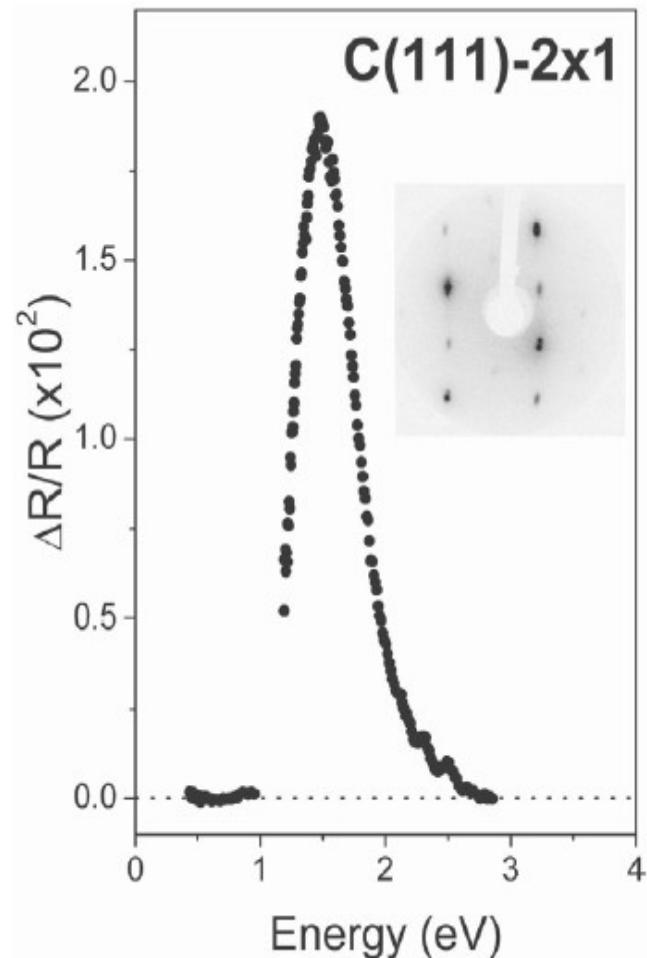
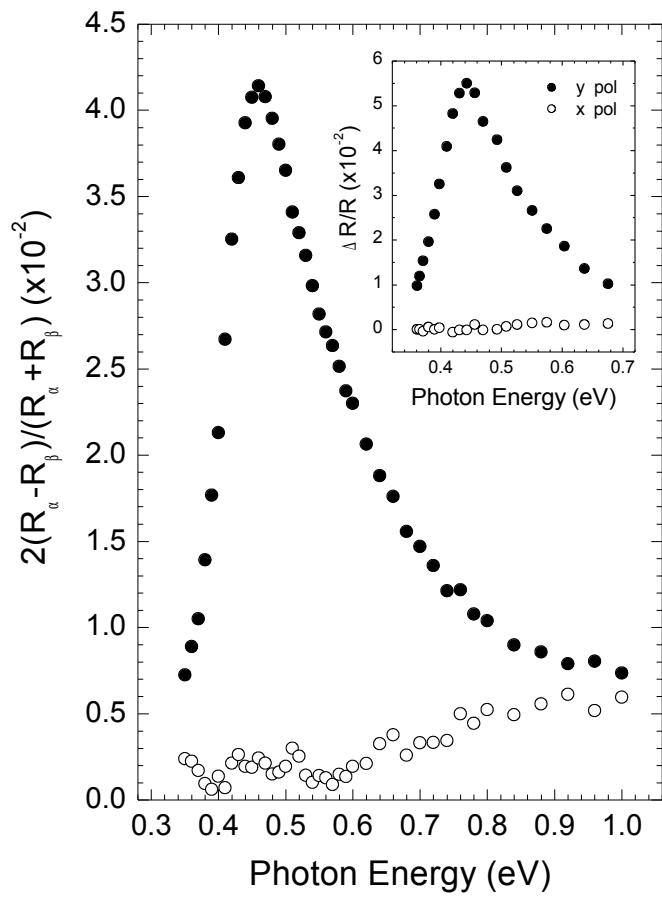


Top view



# RAS on C, Si, Ge (111) – 2x1

## Si(111) – 2x1



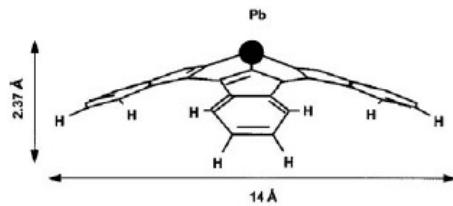
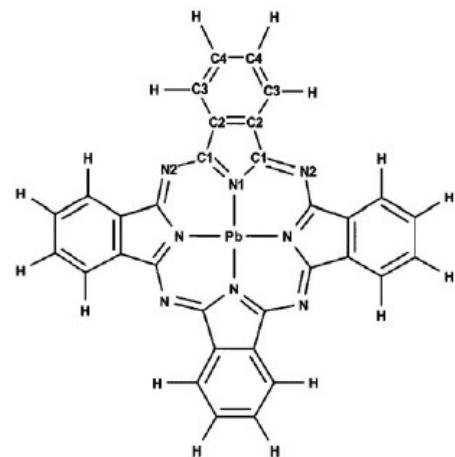
C.Goletti, F.Arciprete, G.Bussetti, P.Chiaradia, G.Chiarotti *Phys. Rev. B* **66**, 153307 (2002)

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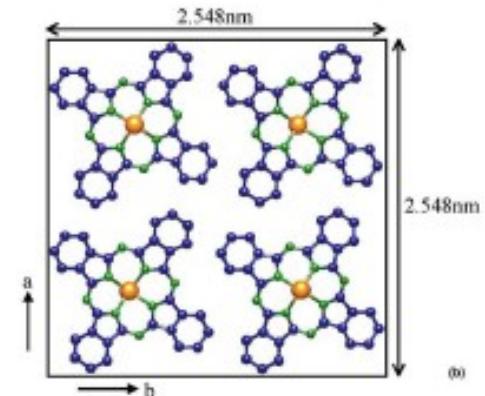
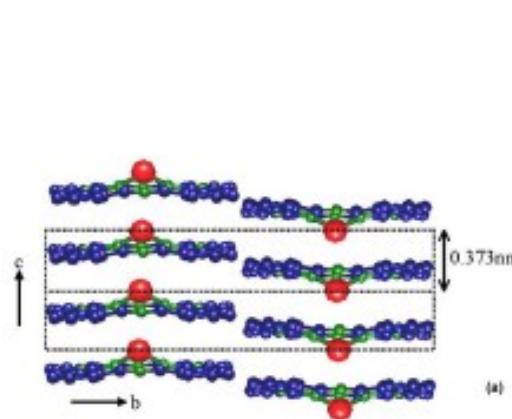
# Thin organic layers

# Pb-Phtalocyanines

## Pb-Phtalocyanine molecule

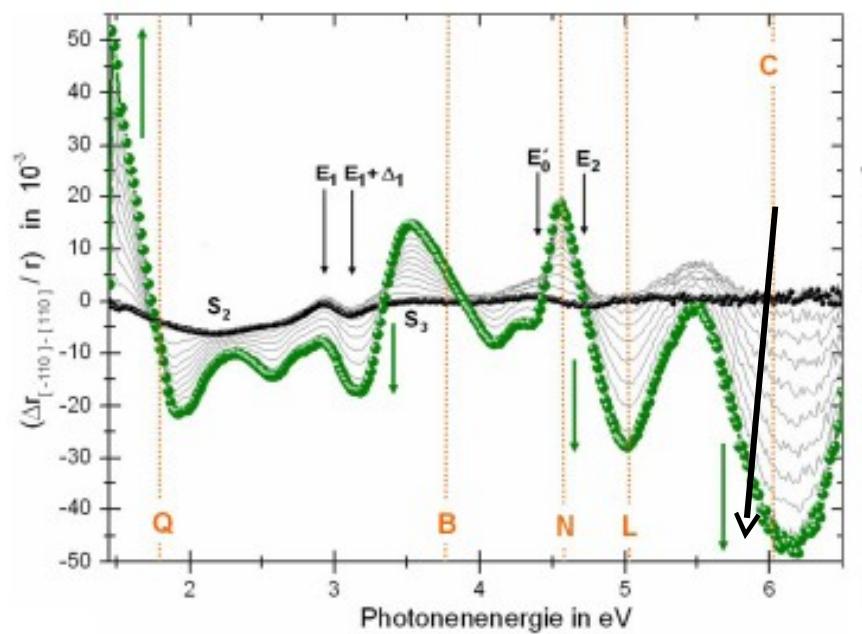


## Pb-Phtalocyanine crystal

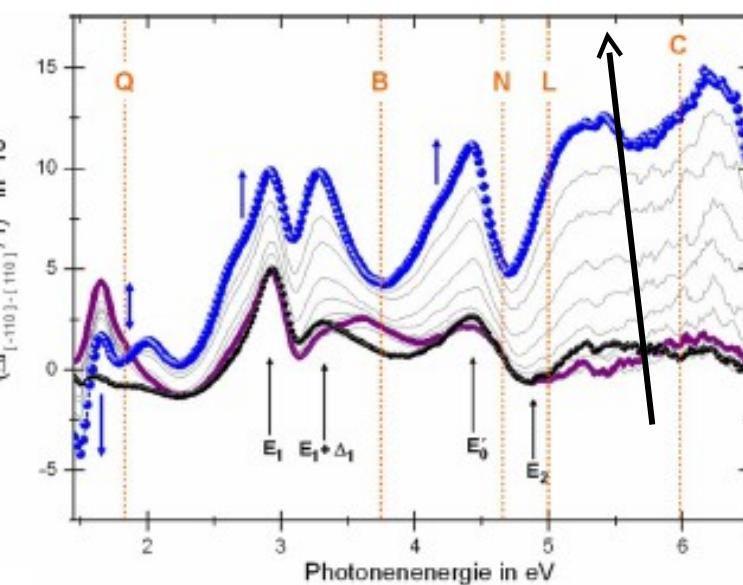


# Pb-Phtalocyanine on GaAs surface reconstructions

on GaAs(4x2)



on GaAs(2x4)

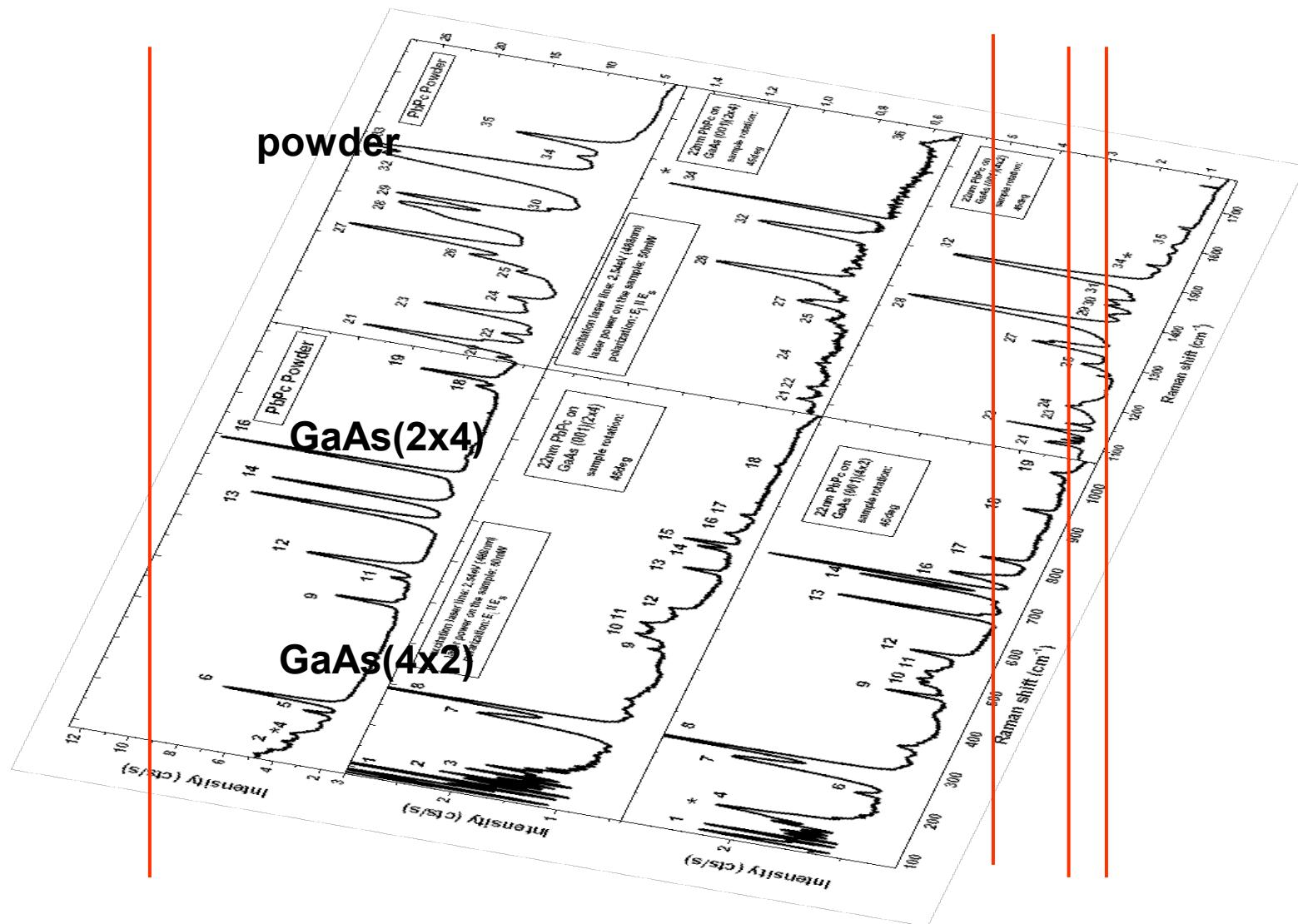


Clean surface: black

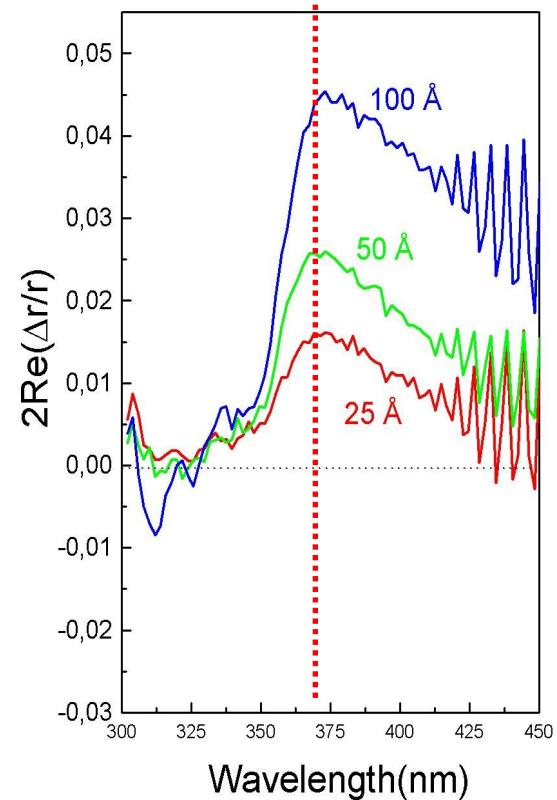
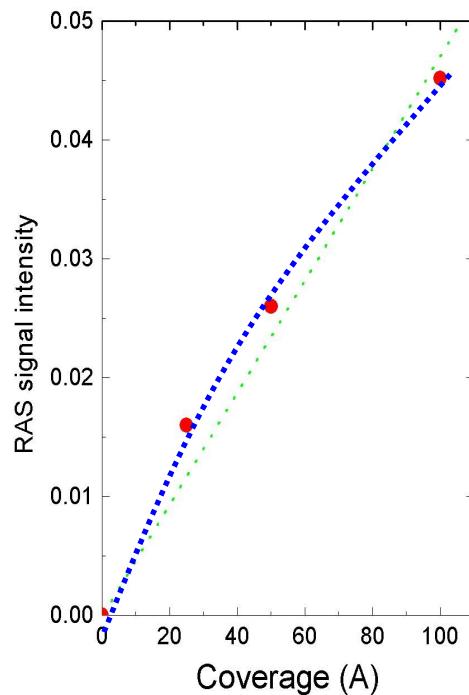
22 nm coverage: green or blue

Intermediate coverages: grey

# Pb-Phtalocyanin (20nm) on GaAs(001) (2x4) –middle- and (4x2) –bottom-



# Thickness monitoring of $\alpha$ -sexithiophene thin films



APPLIED PHYSICS LETTERS

VOLUME 83, NUMBER 20

17 NOVEMBER 2003

Highly sensitive optical monitoring of molecular film growth by organic molecular beam deposition

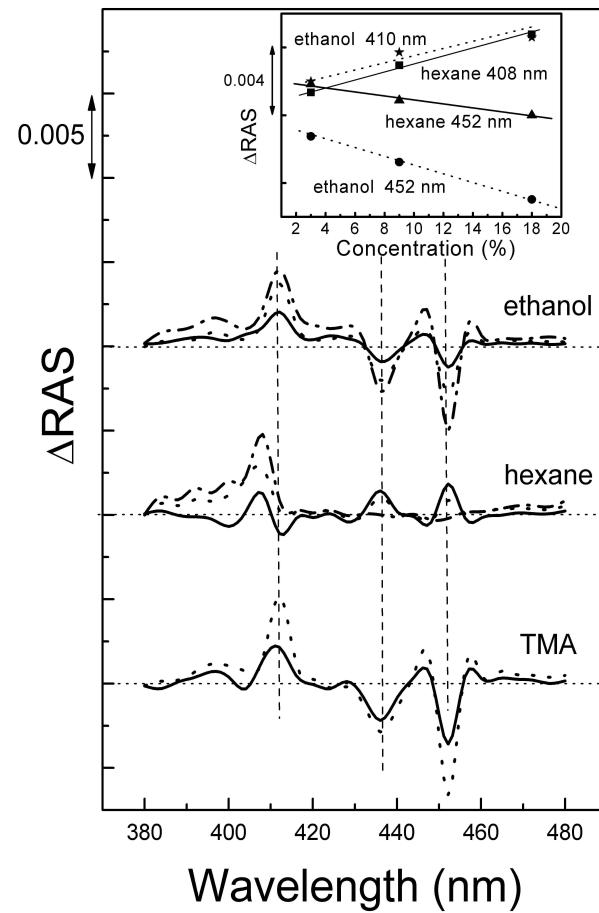
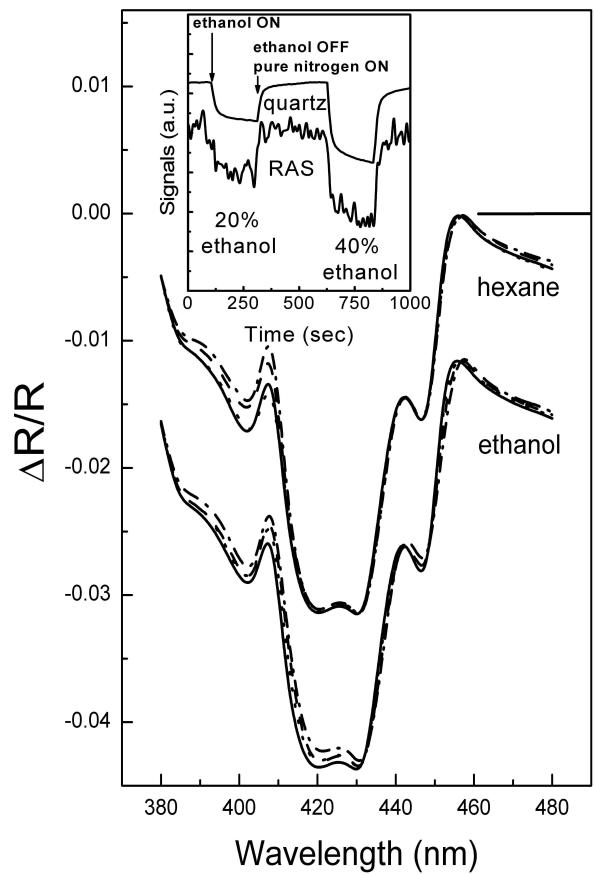
C. Goletti,<sup>a)</sup> G. Bussetti, and P. Chiaradia

Dipartimento di Fisica and Unità INFM, Università di Roma "Tor Vergata," Via Della Ricerca Scientifica, I-00133, Roma, Italy

A. Sassella and A. Borghesi

Dipartimento di Scienza dei Materiali and Unità INFM, Università di Milano-Bicocca, Via Cozzi 53, I-20125 Milano, Italy

# Chemical vapor sensing by RAS: artificial nose



- 
- Optical analysis on nanostructures indispensable, but diffraction limited
  - Diffraction limit can be achieved by confocal microscopy and overcome by nearfield optics
  - Linear techniques (RAS, PL, T) can be easily applied on single (few) nanostructures

**FINE**